

BFU660F,115

BFU660F,115 Information

-	Part Number	BFU660F,115
www.bersener.com	Manufacturer	NXP
	Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - RF
	Description	TRANSISTOR NPN SOT343F
	Package	SOT-343F
		For the pricing/inventory/lead time, please contact us
For Reference Only		Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



BFU660F,115 Specifications

Manufacturer Part Number	BFU660F,115
Manufacturer	NXP
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - RF
Package	SOT-343F
Series	-
Transistor Type	NPN
Voltage - Collector Emitter Breakdown (Max)	5.5V
Frequency - Transition	21GHz
Noise Figure (dB Typ @ f)	0.6dB ~ 1.2dB @ 1.5GHz ~ 5.8GHz
Gain	12dB ~ 21dB
Power - Max	225mW
DC Current Gain (hFE) (Min) @ Ic, Vce	90 @ 10mA, 2V
Current - Collector (Ic) (Max)	60mA
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Package / Case	SOT-343F
Supplier Device Package	4-DFP
	Report errors?

BFU660F,115 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

BFU660F,115 Payment Methods



BFU660F,115 Shipping Methods



If you have any question about BFU660F,115, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com